

# P16B6SB

Power MOSFETs  
60V, 16A, N-channel

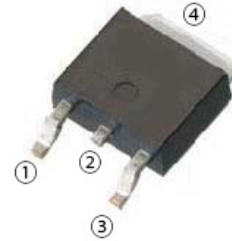
## Feature

- N-channel
- SMD
- Low Ron
- 4.5V Gate Drive
- Low Capacitance
- Pb free terminal
- RoHS:Yes

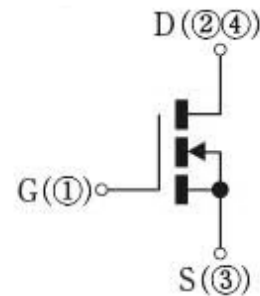
## OUTLINE

Package (House Name): FB

Package (JEDEC Code): TO-252AA



## Equivalent circuit



## Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel temperature	Tch		150	°C
Drain-source voltage	V <sub>DSS</sub>		60	V
Gate-source voltage	V <sub>GSS</sub>		±20	V
Continuous drain current(DC)	I <sub>D</sub>		16	A
Continuous drain current(Peak)	I <sub>DP</sub>	Pulse width 10μs, duty=1/100	48	A
Total power dissipation	P <sub>T</sub>		20	W
Single avalanche current	I <sub>AS</sub>	Starting Tch=25°C Tch ≤ 150°C	12	A
Single avalanche energy	E <sub>AS</sub>	Starting Tch=25°C Tch ≤ 150°C	14.8	mJ

※ : See the original Specifications

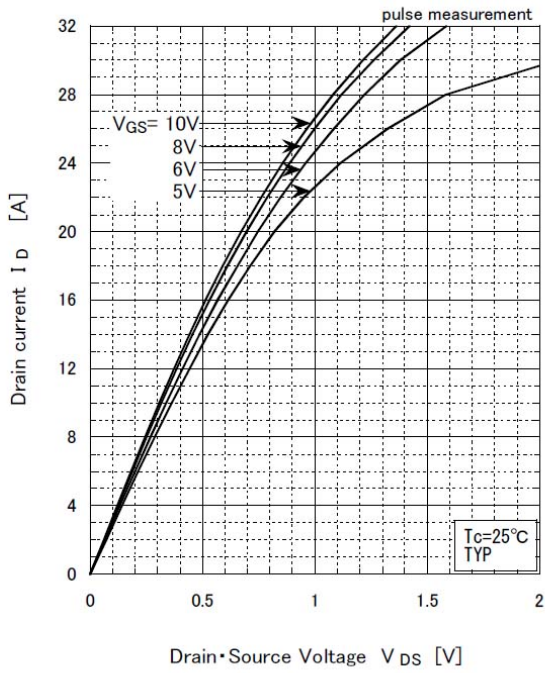
**Electrical Characteristics** (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	60			V
Zero gate voltage drain current	$I_{DSS}$	VDS=60V, VGS=0V			1	μA
Gate-source leakage current	$I_{GSS}$	VGS=±20V, VDS=0V			±10	μA
Forward transconductance	$g_{fs}$	ID=8A, VDS=10V	4			S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=8A, VGS=10V		0.029	0.037	Ω
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=8A, VGS=4.5V		0.036	0.048	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	1.5	2	2.5	V
Source-drain diode forward voltage	$V_{SD}$	IS=16A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case			6.28	°C/W
Total gate charge	Qg	VDD=48V, VGS=10V, ID=16A		17		nC
Gate to source charge	Qgs	VDD=48V, VGS=10V, ID=16A		4.1		nC
Gate to drain charge	Qgd	VDD=48V, VGS=10V, ID=16A		4		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		655		pF
Reverse transfer capacitance	Crss	VDS=25V, VGS=0V, f=1MHz		36		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		85		pF
Turn-on delay time	td(on)	ID=8A, RL=3.75Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		4		ns
Rise time	tr	ID=8A, RL=3.75Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		8.5		ns
Turn-off delay time	td(off)	ID=8A, RL=3.75Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		13.5		ns
Fall time	tf	ID=8A, RL=3.75Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		4		ns
Diode reverse recovery time	trr	IF=16A, VGS=0V, di/dt=100A/μs		40		ns
Diode reverse recovery charge	Qrr	IF=16A, VGS=0V, di/dt=100A/μs		46		nC

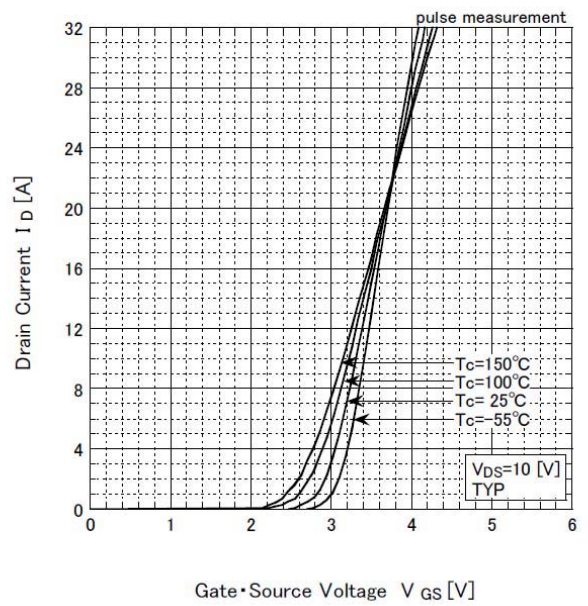
※ : See the original Specifications

# CHARACTERISTIC DIAGRAMS

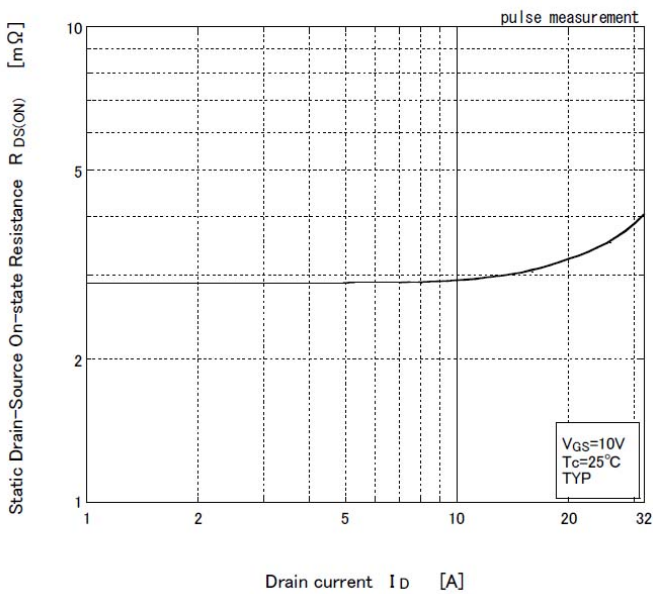
Typical Output Characteristics



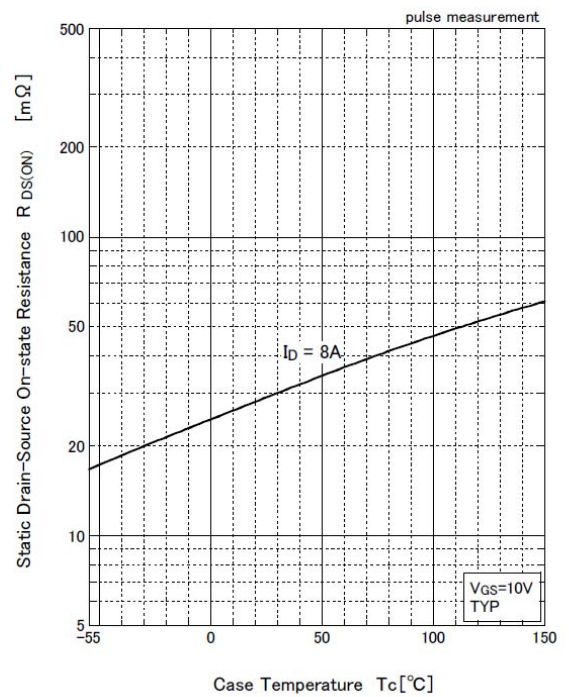
Transfer Characteristics

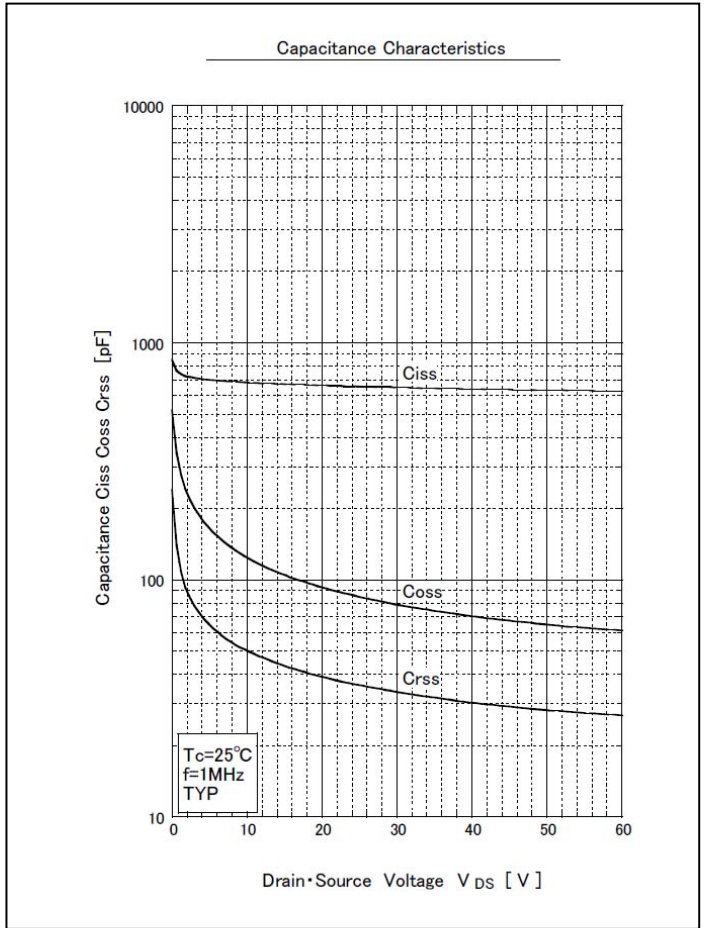
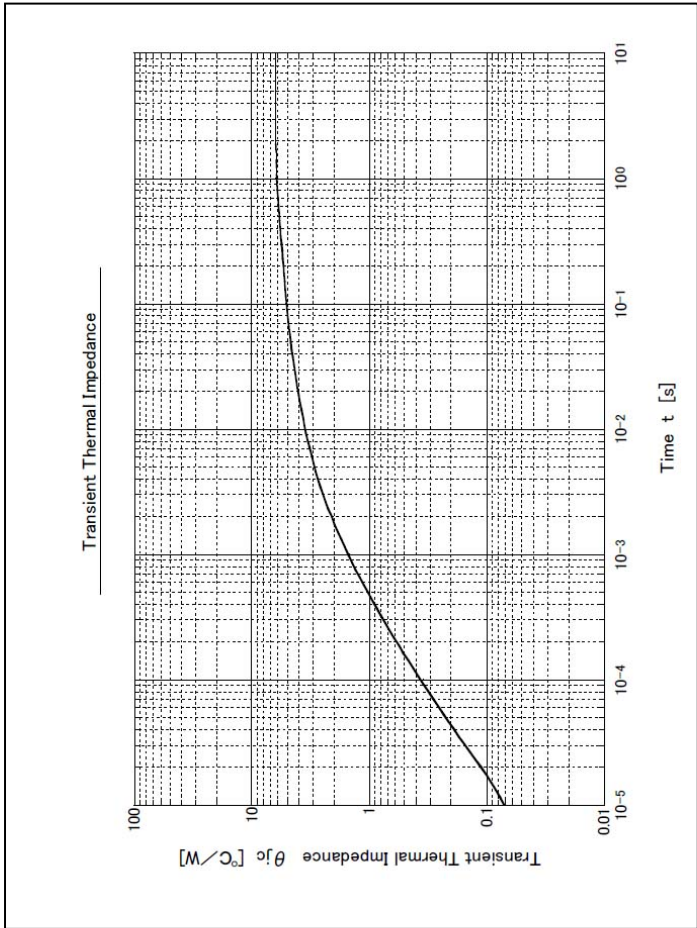
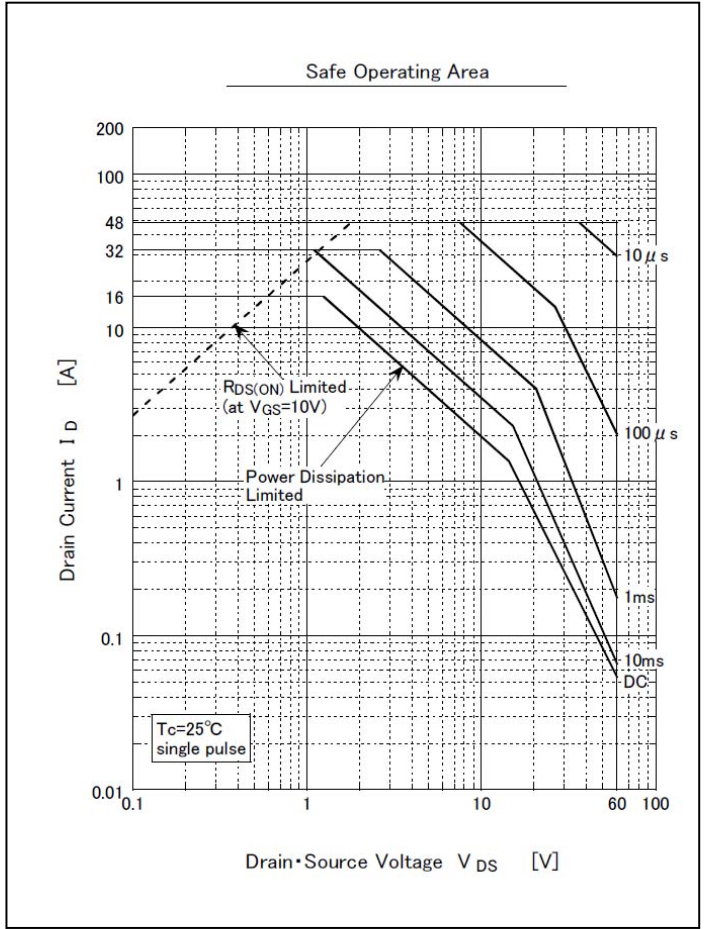
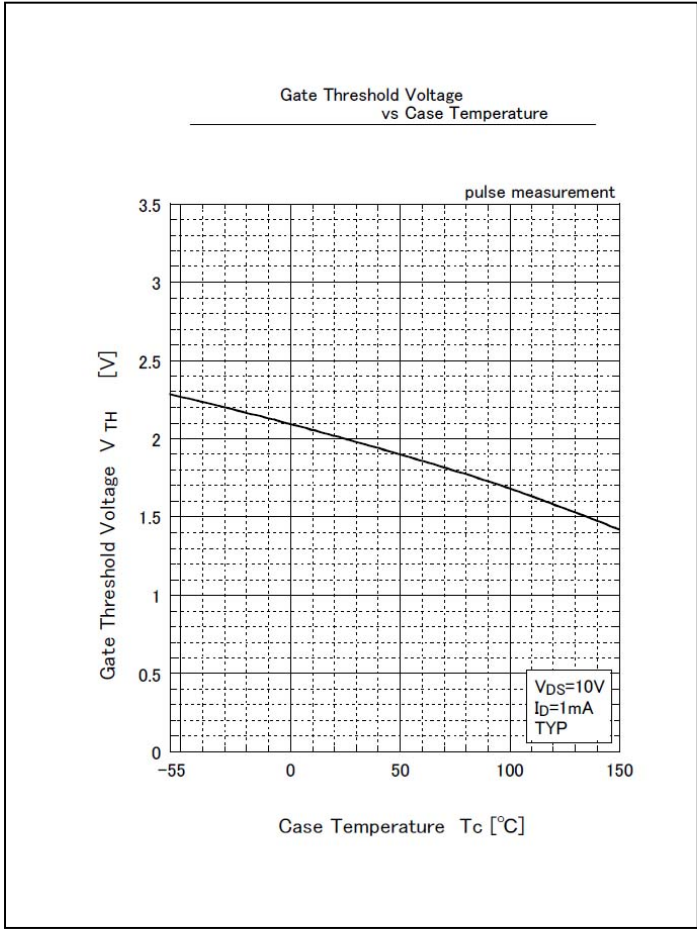


Static Drain-Source On-state Resistance vs Drain Current

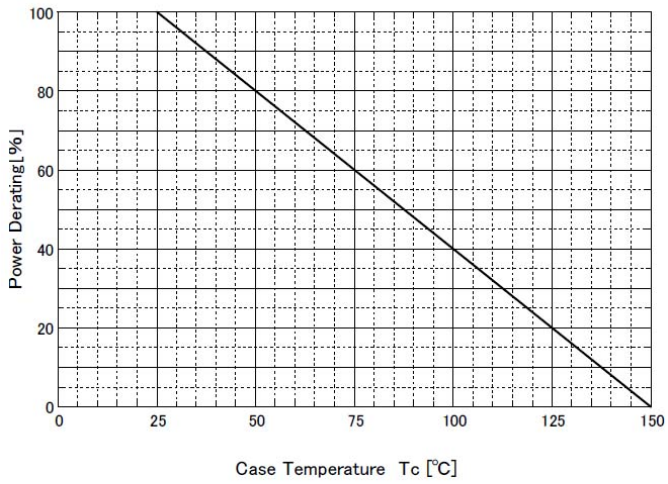


Static Drain-Source On-state Resistance vs Case Temperature

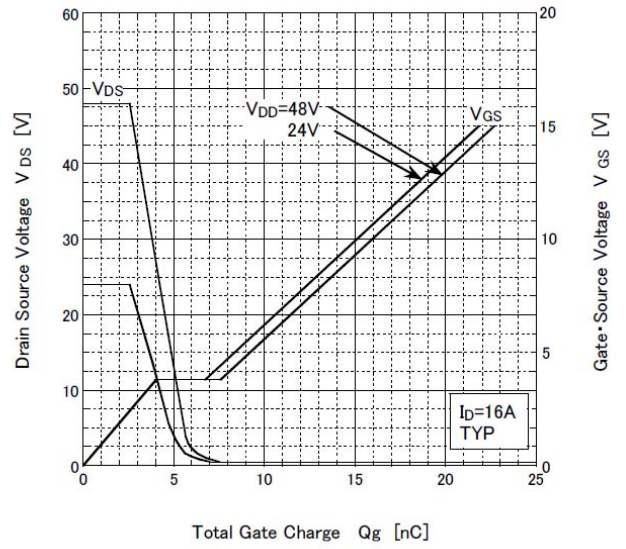




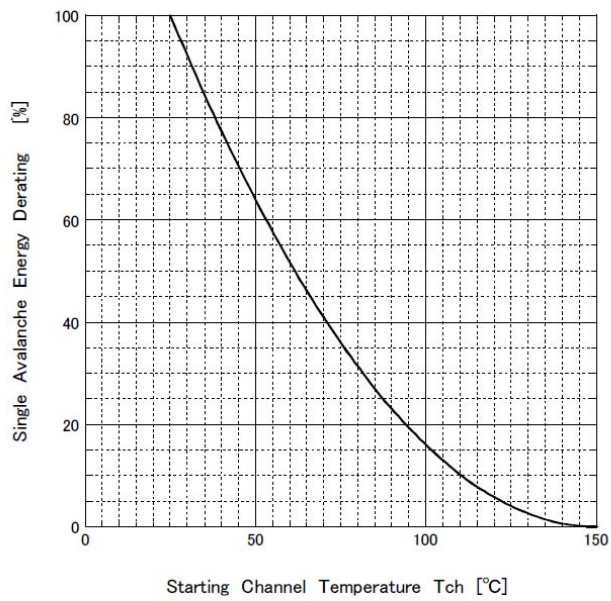
Power Derating - Case Temperature



Gate Charge Characteristics



Single Avalanche Energy Derating vs Channel Temperature

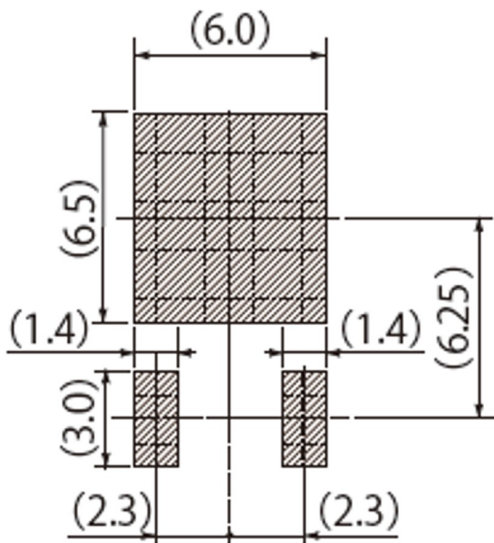
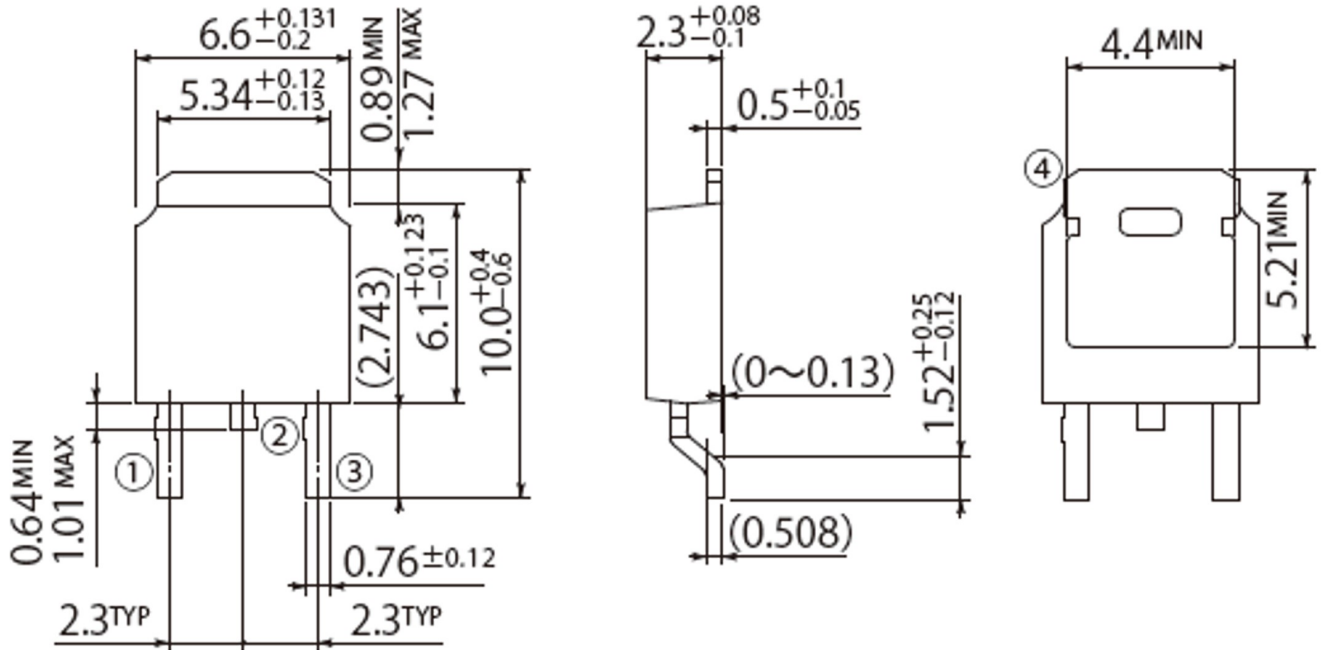


# Outline Dimensions

unit:mm

G2

JEDEC Code	TO-252AA
JEITA Code	-
House Name	FB



Referential Soldering Pad

## Notes

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